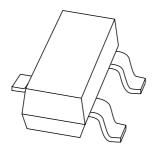
DISCRETE SEMICONDUCTORS

DATA SHEET



BF840NPN medium frequency transistor

Product data sheet Supersedes data of 1999 Apr 12 2004 Jan 13



NXP Semiconductors Product data sheet

NPN medium frequency transistor

BF840

FEATURES

- Low current (max. 25 mA)
- Low voltage (max. 40 V).

APPLICATIONS

- AM mixers
- IF amplifiers in AM/FM receivers.

DESCRIPTION

NPN medium frequency transistor in a SOT23 plastic package.

MARKING

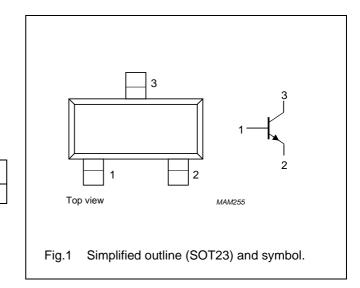
| TYPE NUMBER | MARKING CODE(1) | |
|-------------|-----------------|--|
| BF840 | NC* | |

Note

- 1. * = p: Made in Hong Kong.
 - * = t : Made in Malaysia.
 - * = W : Made in China.

PINNING

| PIN | DESCRIPTION | |
|-----|-------------|--|
| 1 | base | |
| 2 | emitter | |
| 3 | collector | |



ORDERING INFORMATION

| TYPE | | PACKAGE | | | |
|--------|------|--|--|--|--|
| NUMBER | NAME | ME DESCRIPTION VERSION | | | |
| BF840 | _ | plastic surface mounted package; 3 leads SOT23 | | | |

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

| SYMBOL | PARAMETER | CONDITIONS | MIN. | MAX. | UNIT |
|------------------|-------------------------------|----------------------------------|------|------|------|
| V _{CBO} | collector-base voltage | open emitter | _ | 40 | V |
| V _{CEO} | collector-emitter voltage | open base | _ | 40 | V |
| V _{EBO} | emitter-base voltage | open collector | _ | 4 | V |
| I _C | collector current (DC) | | _ | 25 | mA |
| I _{CM} | peak collector current | | _ | 25 | mA |
| P _{tot} | total power dissipation | T _{amb} ≤ 25 °C; note 1 | _ | 250 | mW |
| T _{stg} | storage temperature | | -65 | +150 | °C |
| Tj | junction temperature | | _ | 150 | °C |
| T _{amb} | operating ambient temperature | | -65 | +150 | °C |

Note

1. Transistor mounted on an FR4 printed-circuit board.

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NXP Semiconductors Product data sheet

NPN medium frequency transistor

BF840

THERMAL CHARACTERISTICS

| SYMBOL | PARAMETER | CONDITIONS | VALUE | UNIT |
|----------------------|---|------------|-------|------|
| R _{th(j-a)} | thermal resistance from junction to ambient | note 1 | 500 | K/W |

Note

1. Transistor mounted on an FR4 printed-circuit board.

CHARACTERISTICS

 $T_i = 25$ °C unless otherwise specified.

| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | UNIT |
|------------------|---------------------------|--|------|------|------|------|
| I _{CBO} | collector cut-off current | I _E = 0; V _{CB} = 20 V | _ | _ | 100 | nA |
| I _{EBO} | emitter cut-off current | I _C = 0; V _{EB} = 4 V | _ | - | 100 | nA |
| h _{FE} | DC current gain | I _C = 1 mA; V _{CE} = 10 V | 67 | _ | 222 | |
| V_{BE} | base-emitter voltage | I _C = 1 mA; V _{CE} = 10 V | 675 | 725 | 775 | mV |
| C _{re} | feedback capacitance | I _C = 0; V _{CB} = 10 V; f = 1 MHz | - | 0.3 | _ | pF |
| f _T | transition frequency | I _C = 1 mA; V _{CE} = 10 V; f = 100 MHz | _ | 380 | _ | MHz |

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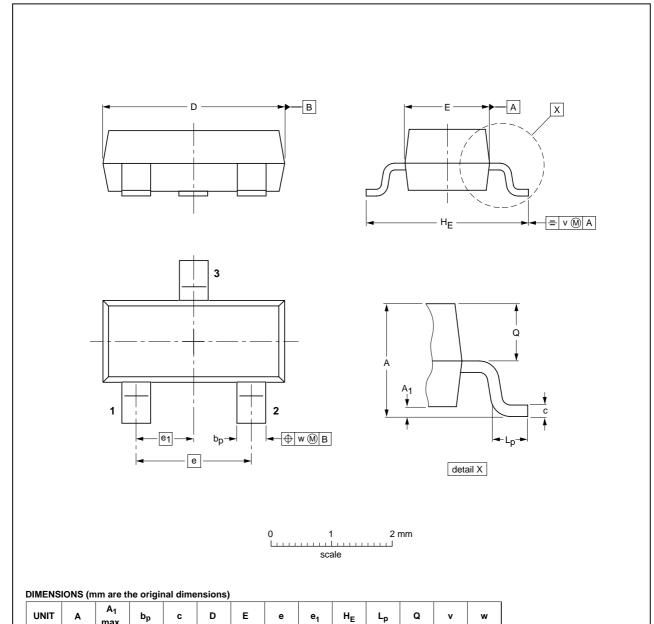
NPN medium frequency transistor

BF840

PACKAGE OUTLINE

Plastic surface-mounted package; 3 leads

SOT23



| OUTLINE | REFERENCES | | | EUROPEAN | ISSUE DATE | |
|---------|----------------------------|----------|------------|----------|------------|-----------------------------------|
| VERSION | IEC JEDEC JEITA PROJECTION | | ISSUE DATE | | | |
| SOT23 | | TO-236AB | | | | -04-11-04- 06-03-16 |

0.45

0.55

0.1

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max

0.38

0.9

NXP Semiconductors Product data sheet

NPN medium frequency transistor

BF840

DATA SHEET STATUS

| DOCUMENT STATUS(1) | PRODUCT STATUS ⁽²⁾ | DEFINITION |
|------------------------|----------------------------------|---|
| Objective data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary data sheet | Qualification | This document contains data from the preliminary specification. |
| Product data sheet | Production | This document contains the product specification. |

Notes

- 1. Please consult the most recently issued document before initiating or completing a design.
- 2. The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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Customer notification

This data sheet was changed to reflect the new company name NXP Semiconductors, including new legal definitions and disclaimers. No changes were made to the technical content, except for package outline drawings which were updated to the latest version.

Contact information

For additional information please visit: http://www.nxp.com
For sales offices addresses send e-mail to: salesaddresses@nxp.com

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